

L Number	Hits	Search Text	DB	Time stamp
1	952	438/46.ccls. or 438/47.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/30 09:17
2	4289377	anneal\$4 or heat\$4 or thermal\$3 adj2 treat\$4 or rta or rto or oxidiz\$4 or oxidat\$4	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/30 09:19
3	711	(438/46.ccls. or 438/47.ccls.) and (anneal\$4 or heat\$4 or thermal\$3 adj2 treat\$4 or rta or rto or oxidiz\$4 or oxidat\$4)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/30 09:50
4	2	("5306662").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/30 09:51
-	3962340	anneal\$4 or heat\$4 or thermal\$3 adj2 treat\$4 or rta	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/30 09:18
-	805734	oxygen or "o.sub.2" or "o2" or "o.sub2."	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/28 17:11
-	797950	nitrogen or "n.sub.2" or "n2" or "n.sub2."	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/28 15:04
-	104156	(anneal\$4 or heat\$4 or thermal\$3 adj2 treat\$4 or rta) with (oxygen or "o.sub.2" or "o2" or "o.sub2.")	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/28 15:04
-	119289	(anneal\$4 or heat\$4 or thermal\$3 adj2 treat\$4 or rta) with (nitrogen or "n.sub.2" or "n2" or "n.sub2.")	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/28 15:05
-	733199	led or light adj3 emitt\$4 or laser adj3 diode or ld	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/28 15:06
-	20208	gan or gallium adj3 nitride	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/28 15:48
-	201920	((anneal\$4 or heat\$4 or thermal\$3 adj2 treat\$4 or rta) with (oxygen or "o.sub.2" or "o2" or "o.sub2.")) or ((anneal\$4 or heat\$4 or thermal\$3 adj2 treat\$4 or rta) with (nitrogen or "n.sub.2" or "n2" or "n.sub2."))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/28 15:46
-	1618	((anneal\$4 or heat\$4 or thermal\$3 adj2 treat\$4 or rta) with (oxygen or "o.sub.2" or "o2" or "o.sub2.")) or ((anneal\$4 or heat\$4 or thermal\$3 adj2 treat\$4 or rta) with (nitrogen or "n.sub.2" or "n2" or "n.sub2."))) and (gan or gallium adj3 nitride)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/28 15:08

-	972	((((anneal\$4 or heat\$4 or thermal\$3 adj2 treat\$4 or rta) with (oxygen or "o.sub.2" or "o2" or "o.sub2.")) or ((anneal\$4 or heat\$4 or thermal\$3 adj2 treat\$4 or rta) with (nitrogen or "n.sub.2" or "n2" or "n.sub2."))) and (gan or gallium adj3 nitride)) and (led or light adj3 emitt\$4 or laser adj3 diode or ld)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/28 15:08
-	21525	((anneal\$4 or heat\$4 or thermal\$3 adj2 treat\$4 or rta) with (oxygen or "o.sub.2" or "o2" or "o.sub2.")) and ((anneal\$4 or heat\$4 or thermal\$3 adj2 treat\$4 or rta) with (nitrogen or "n.sub.2" or "n2" or "n.sub2."))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/28 15:09
-	109	((anneal\$4 or heat\$4 or thermal\$3 adj2 treat\$4 or rta) with (oxygen or "o.sub.2" or "o2" or "o.sub2.")) and ((anneal\$4 or heat\$4 or thermal\$3 adj2 treat\$4 or rta) with (nitrogen or "n.sub.2" or "n2" or "n.sub2.")) and (led or light adj3 emitt\$4 or laser adj3 diode or ld) and (gan or gallium adj3 nitride)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/28 15:09
-	529	(gan or gallium adj3 nitride) same ((anneal\$4 or heat\$4 or thermal\$3 adj2 treat\$4 or rta) with (oxygen or "o.sub.2" or "o2" or "o.sub2.")) or ((anneal\$4 or heat\$4 or thermal\$3 adj2 treat\$4 or rta) with (nitrogen or "n.sub.2" or "n2" or "n.sub2."))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/28 15:46
-	383	((gan or gallium adj3 nitride) same ((anneal\$4 or heat\$4 or thermal\$3 adj2 treat\$4 or rta) with (oxygen or "o.sub.2" or "o2" or "o.sub2.")) or ((anneal\$4 or heat\$4 or thermal\$3 adj2 treat\$4 or rta) with (nitrogen or "n.sub.2" or "n2" or "n.sub2."))) and (led or light adj3 emitt\$4 or laser adj3 diode or ld)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/28 15:47
-	1549	(gan or gallium adj3 nitride or pgan) near5 (contact\$3 adj3 layer)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/28 17:14
-	19	(anneal\$4 or heat\$4 or thermal\$3 adj2 treat\$4 or rta) same (oxygen or "o.sub.2" or "o2" or "o.sub2.") same ((gan or gallium adj3 nitride or pgan) near5 (contact\$3 adj3 layer))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/28 15:51
-	82	(anneal\$4 or heat\$4 or thermal\$3 adj2 treat\$4 or rta) same (nitrogen or "n.sub.2" or "n2" or "n.sub2.") same ((gan or gallium adj3 nitride or pgan) near5 (contact\$3 adj3 layer))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/28 15:51
-	96	((anneal\$4 or heat\$4 or thermal\$3 adj2 treat\$4 or rta) same (oxygen or "o.sub.2" or "o2" or "o.sub2.") same ((gan or gallium adj3 nitride or pgan) near5 (contact\$3 adj3 layer))) or ((anneal\$4 or heat\$4 or thermal\$3 adj2 treat\$4 or rta) same (nitrogen or "n.sub.2" or "n2" or "n.sub2.") same ((gan or gallium adj3 nitride or pgan) near5 (contact\$3 adj3 layer)))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/28 15:51
-	5282849	(oxygen or "o.sub.2" or "o2" or "o.sub2.") or "o"	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/28 17:12
-	4292064	(anneal\$4 or heat\$4 or thermal\$3 adj2 treat\$4 or rta) or oxidat\$5 or oxidat\$5 or rto	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/28 17:13

-	2987	(gan or gallium adj3 nitride or pgan) with (contact\$3 or resistan\$3 or resistivit\$3)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/28 17:16
-	67	((oxygen or "o.sub.2" or "o2" or "o.sub2.") or "o") same ((anneal\$4 or heat\$4 or thermal\$3 adj2 treat\$4 or rta) or oxidi\$5 or oxidat\$5 or rto) same ((gan or gallium adj3 nitride or pgan) with (contact\$3 or resistan\$3 or resistivit\$3))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/28 17:17